PTO/SB/08a (08-03)

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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Application Number 09/973,778

Filling Date 11 October 2001

First Named Inventor Luc OUELLET

Art Unit 1731

Examiner Name John M. Hoffmann

Committee on	0.4	D	U. S. PATENT			
Examiner Initials*	Cite No.	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
	МО.	Number-Kind Code <sup>2 (# bnown)</sup>	MW-DD-1111	Applicant of Cited Document		
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nitiais*	No.'	Country Code <sup>3</sup> 'Alamber <sup>4</sup> 'Kind Code <sup>5</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear	L
		WO 96/41219	12-19-1996			Γ
		WO 02/43130 A2	. 05-30-2002			
		WO 02 43119 A2	05-30-2002			Γ
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Examiner Signature	V	IK I	 Date Considered	1-12-06

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PTO/SB/08b (08-03)

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Substitute for fo	orm 1449B/PTO			Complete if Known			
•				Application Number	09/973,778	· · · · · · · · · · · · · · · · · · ·	
INFOR	MATION I	DISCLO	SURE	Filing Date	11 October 2001	,	
STATE	STATEMENT BY APPLICANT			First Named Inventor	Luc OÜELLET		
				Art Unit	1731		
(Use as many sheets as necessary)				Examiner Name	John M. Hoffmann		
Sheet	2	of	2	Attorney Docket Number	12251-US		

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.1				
11		D.A.P. BULLA, et al., *Deposition of thick TEOS PECVD silicon oxide layers for integrated optical waveguide applications*, Thin Solid Films, Vol. 334, 1998, pages 60-64.			
		M.I. ALAYO, et al., "Thick SiOxNy and SiO2 films obtained by PECVD technique at low temperatures", Thin Solid Films, Vol. 332, 1998, pages 40-45.			
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<sup>\*</sup>EXAMINER: Initial preference of sidered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this ferm with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached. This collection of information is required by 37 CFR 1.97 and 1.98. The Information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.